5 TUBIO 10

A. How long would you need to sun the process to reach the desired Semiconductor properties, and how much its has been loaded into the solicer out that time?

t when
$$C_a (b \cdot 5 \times 10^{-4} \text{ cm}, t) = 2.065 \times 10^{20} \text{ atom } \frac{1}{5} / \text{cm}^3$$
.
 $\frac{C_{AS} - C_{A}(z, t)}{C_{AS} - C_{AO}} = \frac{(2.3 \times 10^{21}) - (2.065 \times 10^{20})}{(2.3 \times 10^{21}) - (2.3 \times 10^{17})} = 0.9103$
 $\frac{C_{AS} - C_{AO}}{(2.3 \times 10^{21})} = 0.9103$

$$\frac{2}{2\sqrt{4_{B}t}} = 1.2$$

$$t = \left(\frac{2}{(1.2)(2)\sqrt{D_{AB}}}\right) = \frac{(0.5\times10^{4} \text{ cm})}{(1.2)(2)\sqrt{5.0\times10^{-3} \text{ cm}^{2}/s}} = 868 \text{ sec}$$

$$= 14.5 \text{ min}.$$

total amount delivered/loaded [Flux integrated over time]

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$$N_{A}|_{z=0}$$
 - $N_{A}|_{z=0}$ -

$$|\mathcal{M}_{A} = S \cdot \int_{|\mathcal{M}|}^{1} dt = 5r^{2} \left(C_{AS} - C_{AD} \right) \sqrt{\frac{D_{AD}}{\Lambda}} \left(2\sqrt{t} \right)$$

$$|\mathcal{M}_{A}| = 4 \cdot 25 \times 10^{18} \text{ atoms } A_{S}.$$

$$\frac{C_{A_5}-C_{A(2,t)}}{C_{A_5}-C_{A_5}}=0.9103 \qquad \left(\frac{2}{2\sqrt{2}A_5.t}\right)=1.2.$$

$$f_{00} = 1.0 \times 10^{4}$$
 $t_{190m} = (2)^{2} t_{5\mu m} = 3472 se_{0} = 58 min.$

Concentration at 5 µm at 58min

$$Csf\left[\frac{0.5\times10^{4}}{2\sqrt{(5.0\times10^{3})(3472)}}\right] = esf(0.6s) = 0.6o3.$$

$$\frac{C_{A5} - C_{4}}{C_{A5} - C_{40}} = 0.603. \qquad C_{4} = -(0.603)(C_{45} - C_{40}) + C_{45}.$$

$$C_{5} = -(0.603)(C_{45} - C_{40}) + C_{45}.$$

$$C_{6} = -(0.13 \times 10^{20} \text{ cfoms fs/cm}^{3}.$$

$$\left(\frac{2}{2\sqrt{2}\sqrt{2}}\right) = 1.2$$

It saight line

C. Flux of As as smin and Lomm.